



DESCRIPTION

The MMBT5551L is available in SOT-23 package.

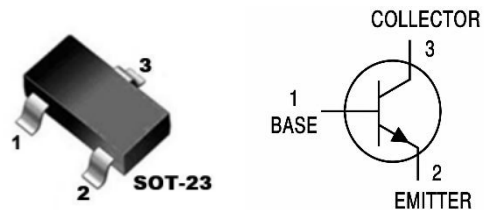
FEATURE

- Epitaxial planar die construction.
- Complementary NPN type available (MMBT5401L).
- Also available in lead free version.

APPLICATIONS

- Ideal for medium power amplification and switching.

PIN DESCRIPTION



ORDERING INFORMATION

Package Type	Part Number
SOT-23	MMBT5551L
Note	SPQ: 3,000pcs/Reel
AiT provides all RoHS Compliant Products	

PIN#	DESCRIPTION
1	BASE
2	EMITTER
3	COLLECTOR

ABSOLUTE MAXIMUM RATINGS

T_A = 25°C, unless otherwise specified

V _{CBO} , Collector-Base Voltage	180V
V _{CEO} , Collector-Emitter Voltage	160V
V _{EBO} , Emitter-Base Voltage	6V
I _C , Collector Current	0.6A
P _C , Collector Power Dissipation	0.35mW
R _{θJA} , Thermal resistance from Junction to ambient	357°C/W
T _J , Junction Temperature	150°C
T _{STG} , Storage Temperature Range	-55 ~150°C

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



ELECTRICAL CHARACTERISTICS

T_A = 25°C, unless otherwise specified

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C =100μA, I _E =0	180	-	-	
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C =0.1mA, I _B =0	160	-	-	
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E =10μA, I _C =0	6	-	-	
Collector cut-off current	I _{CBO}	I _E = 0; V _{CB} = 120V	-	-	50	μA
Emitter cut-off current	I _{EBO}	I _C = 0; V _{EB} = 4V	-	-	50	μA
DC current gain	h _{FE(1)}	V _{CE} =5V; I _C =1mA	80	-	-	
	h _{FE(2)}	V _{CE} =5V; I _C =10mA	100	-	300	
	h _{FE(3)}	V _{CE} =5V; I _C =50mA	30	-	-	
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =10mA; I _B =1mA	-	-	0.15	V
		I _C =50mA; I _B =5mA			0.2	
Base-emitter voltage	V _{BE1}	I _C =10mA; I _B =1mA	-	0.62	1	V
	V _{BE2}	I _C =50mA; I _B =5mA	-	-	1	V
Transition frequency	f _T	V _{CE} =5V, I _C =10mA, f=100MHz	100	-	300	MHz
Output capacitance	C _{obo}	I _E =10mA; V _{CE} =10V; F=1.0MHz	-	-	6.0	pF



TYPICAL CHARACTERISTICS

Fig 1. Typical Pulsed Current Gain
vs. Collector Current

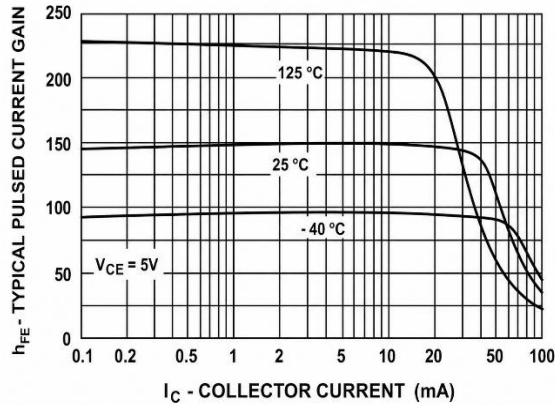


Fig 2. Collector-Emitter Saturation Voltage
vs. Collector Current

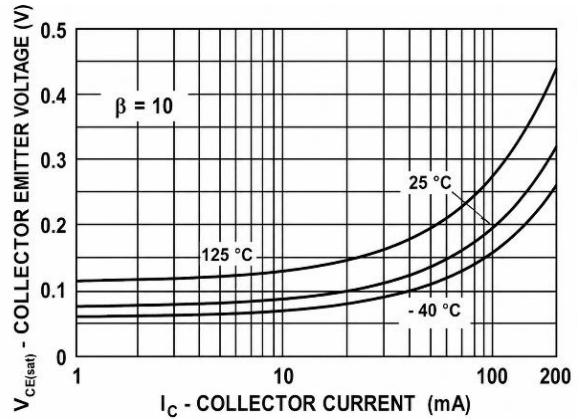


Fig 3. Base-Emitter Saturation Voltage
vs. Collector Current

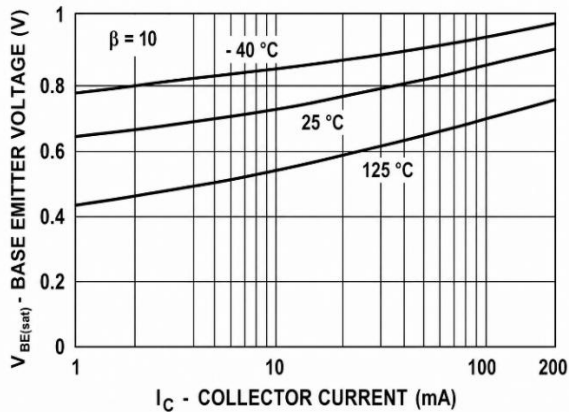


Fig 4. Base-Emitter ON Voltage
vs. Collector Current

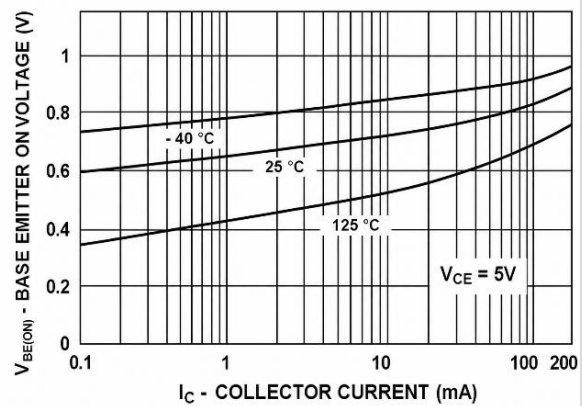


Fig 5. Collector Cutoff Current vs. Ambient
vs. Ambient Temperature

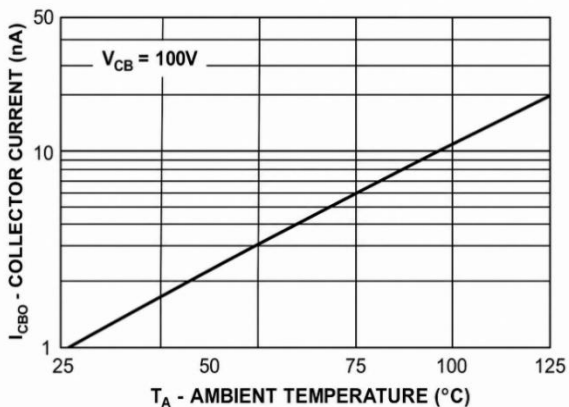


Fig 6. Collector-Emitter Breakdown Voltage with
Resistance Between Emitter-Base

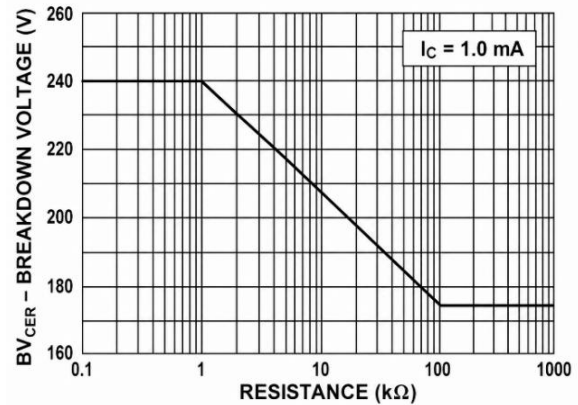




Fig 7. Input and Output Capacitance vs. Reverse vs. Reverse Voltage

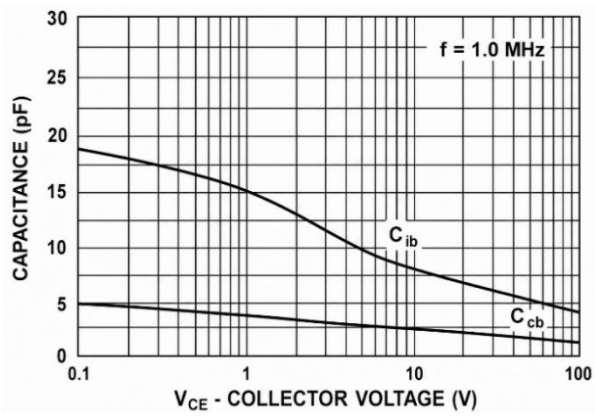
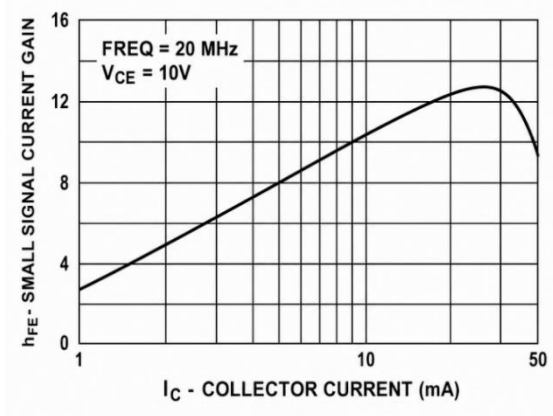


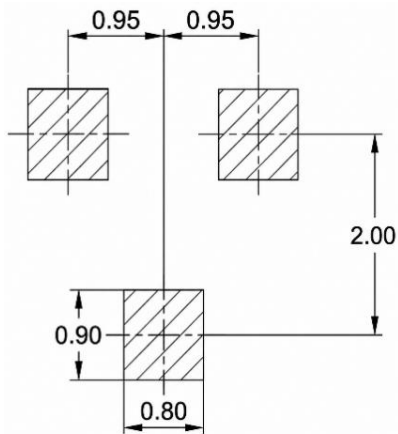
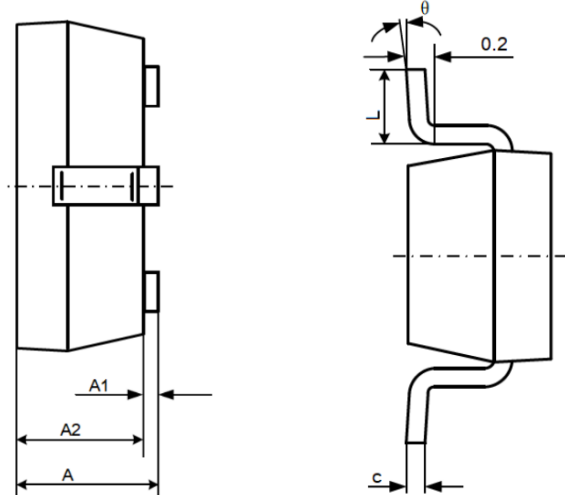
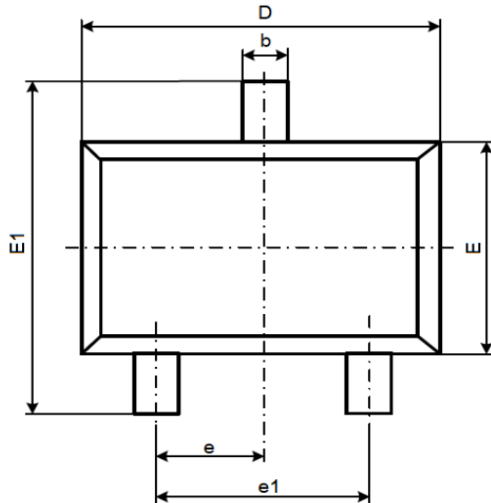
Fig 8. Small Signal Current Gain vs. Collector vs. Collector Current





PACKAGE INFORMATION

Dimension in SOT-23 Package (Unit: mm)



Suggested Pad Layout

Symbol	Dimensions	
	Min	Max
A	1.050	1.250
A1	0.000	0.100
A2	1.050	1.150
b	0.300	0.500
c	0.100	0.200
D	2.820	3.020
E	1.500	1.700
E1	2.650	2.950
e	0.950 BSC	
e1	1.800	2.000
L	0.300	0.600
θ	0°	8°



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